

MBR30100CTW

SCHOTTKY BARRIER RECTIFIERS

REVERSE VOLTAGE - 100 Volts FORWARD CURRENT - 30 Amperes

TO-220AB

FEATURES

- Metal of silicon rectifier, majority carrier conduction
- Guard ring for transient protection
- · Low power loss, high efficiency
- High surge & current capability, low VF
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications

MECHANICAL DATA

- Case: TO-220AB molded plastic
- Plastic package has UL flammability classification 94V-0
- Terminals: Matte Tin, solderable per MIL-STD-202 Method 208
- Lead Free Finish, RoHS Compliant
- Polarity: As marked on the body
- Weight: 0.08 ounces, 2.24 grams
- Mounting position: Any
- Max. mounting torque = 0.5 N.m (5.1 Kgf-cm)

PIN 1 PIN 2 PIN 3 CASE

| TO-220AB | | | | |
|------------------------------|-------------|--------|--|--|
| DIM. | MIN. | MAX. | | |
| Α | 14.22 15.88 | | | |
| В | 9.65 10.67 | | | |
| С | 2.54 3.43 | | | |
| D | 5.84 | 6.86 | | |
| E | 8.26 | 9.28 | | |
| F | - | 6.35 | | |
| G | 12.70 | 14.73 | | |
| Н | 2.29 | 2.79 | | |
| I | 0.51 | 1.14 | | |
| J | 0.30 0.64 | | | |
| K | 3.53 Ø | 4.09 Ø | | |
| L | 3.56 | 4.83 | | |
| М | 1.14 1.40 | | | |
| N | 2.03 2.92 | | | |
| 0 | 1.14 1.70 | | | |
| All Dimensions in millimeter | | | | |

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

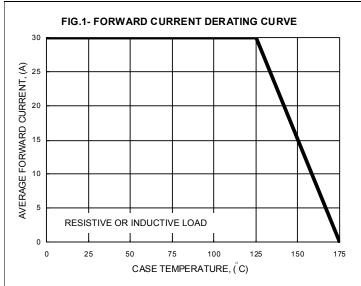
Ratings at 25°C ambient temperature unless otherwise specified.

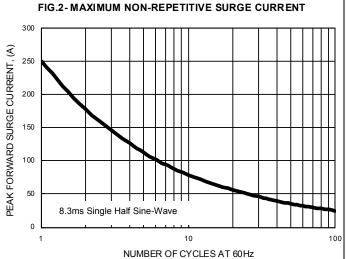
| PARAMETER | SYMBOL | MBR30100CTW | UNIT |
|---|--|----------------------------|----------|
| Maximum Repetitive Peak Reverse Voltage | V_{RRM} | 100 | V |
| Maximum DC Blocking Voltage | V _{DC} | 100 | V |
| Average Rectified Output Current @Tc=125°C | I _F | 30 | Α |
| Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load | I _{FSM} | 250 | А |
| IF=15A@ Tj=25°C | V _F | 0.8 0.67 0.93 0.8 | V |
| Maximum DC Reverse Current at Rated DC Tj=25°C Blocking Voltage Tj=125°C | IR | 100 5 | uA mA |
| Typical junction Capacitance per element (Note 2) | Cj | 450 | pF |
| Typical thermal resistance (Note 3, 4) | Re _{JC} Re _{JL} Re _{JA} | 1.6 2.0 8.0 | °C/W |
| Operating junction temperature range | TJ | -55 to +175 | °C |
| Storage temperature range | T _{STG} | -55 to +175 | °C |
| Note: | 1 | REV. 0 Jul-2013, k | THC105 |

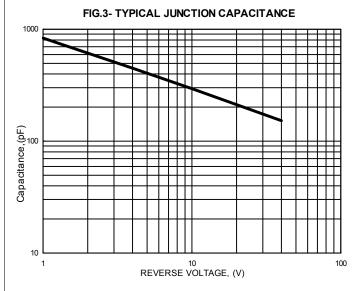
(1) 300us Pulse Width, 2% Duty Cycle.

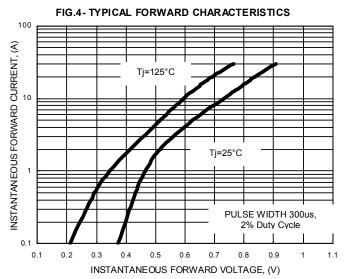
- (2) Measured at 1.0MHz and applied reverse voltage of 4.0 V_{DC}.
- (3) Thermal resistance Junction to Case, Lead and ambient.

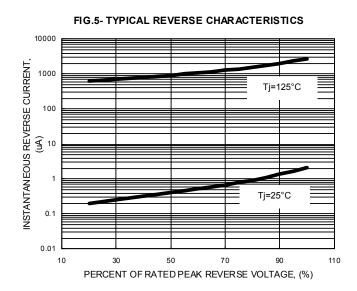














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